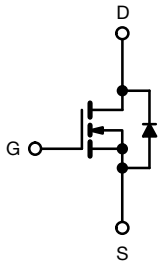
# E Series Power MOSFET

**Thin-Lead TO-220 FULLPAK**




N-Channel MOSFET

## FEATURES

- Low figure-of-merit (FOM) $R_{on}$ x $Q_g$
- Low input capacitance ($C_{iss}$)
- Reduced switching and conduction losses
- Ultra low gate charge ($Q_g$)
- Avalanche energy rated (UIS)
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

RoHS COMPLIANT
HALOGEN FREE Available

## APPLICATIONS

- Server and telecom power supplies
- Switch mode power supplies (SMPS)
- Power factor correction power supplies (PFC)
- Lighting
  - High-intensity discharge (HID)
  - Fluorescent ballast lighting
- Industrial
  - Welding
  - Induction heating
  - Motor drives
  - Battery chargers
  - Renewable energy
  - Solar (PV inverters)

| PRODUCT SUMMARY | | |
|---|---|---|
| $V_{DS}$ (V) at $T_J$ max. | 650 | |
| $R_{DS(on)}$ typ. (Ω) at 25 °C | $V_{GS}$ = 10 V | 0.156 |
| $Q_g$ max. (nC) | 96 | |
| $Q_{gs}$ (nC) | 12 | |
| $Q_{gd}$ (nC) | 25 | |
| Configuration | Single | |

| ORDERING INFORMATION | |
|---|---|
| Package | Thin-Lead TO-220 FULLPAK |
| Lead (Pb)-free | SiHA22N60AE-E3 |
| Lead (Pb)-free and halogen-free | SiHA22N60AE-GE3 |

**ABSOLUTE MAXIMUM RATINGS** ($T_C$ = 25 °C, unless otherwise noted)

| PARAMETER | | | SYMBOL | LIMIT | UNIT |
|---|---|---|---|---|---|
| Drain-source voltage | | | $V_{DS}$ | 600 | V |
| Gate-source voltage | | | $V_{GS}$ | ± 30 | |
| Continuous drain current ($T_J$ = 150 °C) [e] | $V_{GS}$ at 10 V | $T_C$ = 25 °C | $I_D$ | 8 | A |
| | | $T_C$ = 100 °C | | 5 | |
| Pulsed drain current [a] | | | $I_{DM}$ | 49 | |
| Linear derating factor | | | | 0.26 | W/°C |
| Single pulse avalanche energy [b] | | | $E_{AS}$ | 204 | mJ |
| Maximum power dissipation | | | $P_D$ | 33 | W |
| Operating junction and storage temperature range | | | $T_J$, $T_{stg}$ | -55 to +150 | °C |
| Drain-source voltage slope | $T_J$ = 125 °C | | dV/dt | 70 | V/ns |
| Reverse diode dV/dt [d] | | | | 31 | |
| Soldering recommendations (peak temperature) [c] | For 10 s | | | 300 | °C |
| Mounting torque | M3 screw | | | 0.6 | Nm |

**Notes**

a. Repetitive rating; pulse width limited by maximum junction temperature
b. $V_{DD}$ = 140 V, starting $T_J$ = 25 °C, L = 28.2 mH, $R_g$ = 25 Ω, $I_{AS}$ = 3.8 A
c. 1.6 mm from case
d. $I_{SD} \leq I_D$, dI/dt = 100 A/µs, starting $T_J$ = 25 °C
e. Limited by maximum junction temperature



For technical questions, contact: hvm@vishay.com

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

| THERMAL RESISTANCE RATINGS | | | | |
|---|---|---|---|---|
| **PARAMETER** | **SYMBOL** | **TYP.** | **MAX.** | **UNIT** |
| Maximum junction-to-ambient | $R_{thJA}$ | - | 65 | °C/W |
| Maximum junction-to-case (drain) | $R_{thJC}$ | - | 3.8 | |

| **SPECIFICATIONS** ($T_J$ = 25 °C, unless otherwise noted) | | | | | | |
|---|---|---|---|---|---|---|
| **PARAMETER** | **SYMBOL** | **TEST CONDITIONS** | **MIN.** | **TYP.** | **MAX.** | **UNIT** |
| **Static** | | | | | | |
| Drain-source breakdown voltage | $V_{DS}$ | $V_{GS}$ = 0 V, $I_D$ = 250 µA | 600 | - | - | V |
| $V_{DS}$ temperature coefficient | $\Delta V_{DS}/T_J$ | Reference to 25 °C, $I_D$ = 250 µA | - | 0.72 | - | V/°C |
| Gate-source threshold voltage (N) | $V_{GS(th)}$ | $V_{DS}$ = $V_{GS}$, $I_D$ = 250 µA | 2 | - | 4 | V |
| Gate-source leakage | $I_{GSS}$ | $V_{GS}$ = ± 20 V | - | - | ± 100 | nA |
| | | $V_{GS}$ = ± 30 V | - | - | ± 1 | µA |
| Zero gate voltage drain current | $I_{DSS}$ | $V_{DS}$ = 600 V, $V_{GS}$ = 0 V | - | - | 1 | µA |
| | | $V_{DS}$ = 480 V, $V_{GS}$ = 0 V, $T_J$ = 125 °C | - | - | 10 | |
| Drain-source on-state resistance | $R_{DS(on)}$ | $V_{GS}$ = 10 V; $I_D$ = 11 A | - | 0.156 | 0.180 | Ω |
| Forward transconductance | $g_{fs}$ | $V_{DS}$ = 30 V, $I_D$ = 11 A | - | 4.8 | - | S |
| **Dynamic** | | | | | | |
| Input capacitance | $C_{iss}$ | $V_{GS}$ = 0 V, $V_{DS}$ = 100 V, f = 1 MHz | - | 1451 | - | pF |
| Output capacitance | $C_{oss}$ | | - | 73 | - | |
| Reverse transfer capacitance | $C_{rss}$ | | - | 5 | - | |
| Effective output capacitance, energy related [a] | $C_{o(er)}$ | $V_{DS}$ = 0 V to 480 V, $V_{GS}$ = 0 V | - | 50 | - | |
| Effective output capacitance, time related [b] | $C_{o(tr)}$ | | - | 258 | - | |
| Total gate charge | $Q_g$ | $V_{GS}$ = 10 V; $I_D$ = 11 A, $V_{DS}$ = 480 V | - | 48 | 96 | nC |
| Gate-source charge | $Q_{gs}$ | | - | 12 | - | |
| Gate-drain charge | $Q_{gd}$ | | - | 25 | - | |
| Turn-on delay time | $t_{d(on)}$ | $V_{DD}$ = 480 V, $I_D$ = 11 A, $V_{GS}$ = 10 V, $R_g$ = 9.1 Ω | - | 19 | 38 | ns |
| Rise time | $t_r$ | | - | 33 | 66 | |
| Turn-off delay time | $t_{d(off)}$ | | - | 45 | 90 | |
| Fall time | $t_f$ | | - | 21 | 42 | |
| Gate input resistance | $R_g$ | f = 1 MHz, open drain | 0.3 | 0.6 | 1.2 | Ω |
| **Drain-Source Body Diode Characteristics** | | | | | | |
| Continuous source-drain diode current | $I_S$ | MOSFET symbol showing the integral reverse p - n junction diode  | - | - | 20 | A |
| Pulsed diode forward current | $I_{SM}$ | | - | - | 49 | |
| Diode forward voltage | $V_{SD}$ | $T_J$ = 25 °C, $I_S$ = 11 A, $V_{GS}$ = 0 V | - | - | 1.2 | V |
| Reverse recovery Time | $t_{rr}$ | $T_J$ = 25 °C, $I_F$ = $I_S$ = 11 A, dI/dt = 100 A/µs, $V_R$ = 25 V | - | 319 | 638 | ns |
| Reverse recovery charge | $Q_{rr}$ | | - | 4.9 | 9.8 | µC |
| Reverse recovery current | $I_{RRM}$ | | - | 28 | - | A |

**Notes**

a. $C_{oss(er)}$ is a fixed capacitance that gives the same energy as $C_{oss}$ while $V_{DS}$ is rising from 0 % to 80 % $V_{DSS}$

b. $C_{oss(tr)}$ is a fixed capacitance that gives the same charging time as $C_{oss}$ while $V_{DS}$ is rising from 0 % to 80 % $V_{DSS}$



For technical questions, contact: hvm@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

**TYPICAL CHARACTERISTICS** (25 °C, unless otherwise noted)

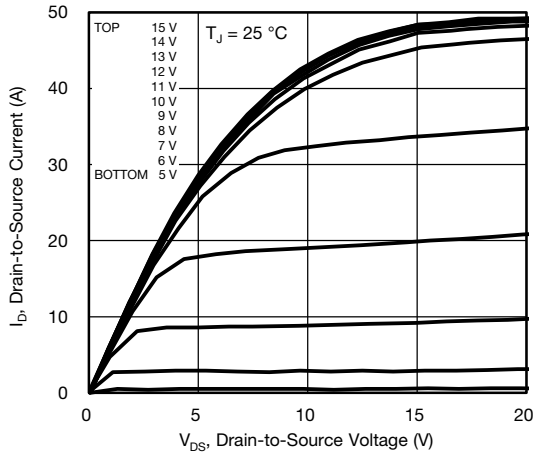



**Fig. 1 - Typical Output Characteristics**

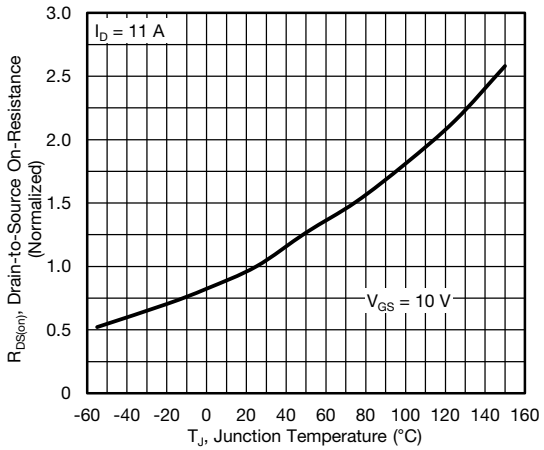



**Fig. 4 - Normalized On-Resistance vs. Temperature**

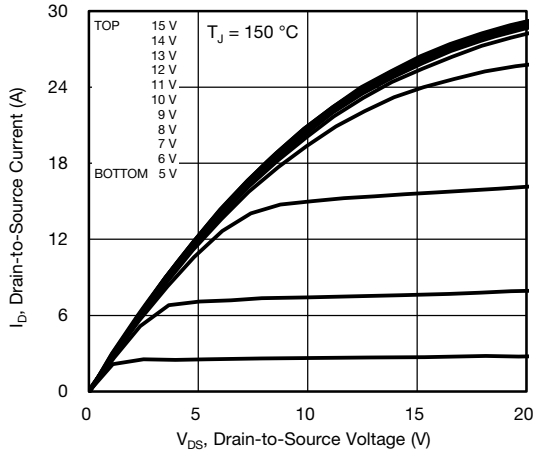



**Fig. 2 - Typical Output Characteristics**

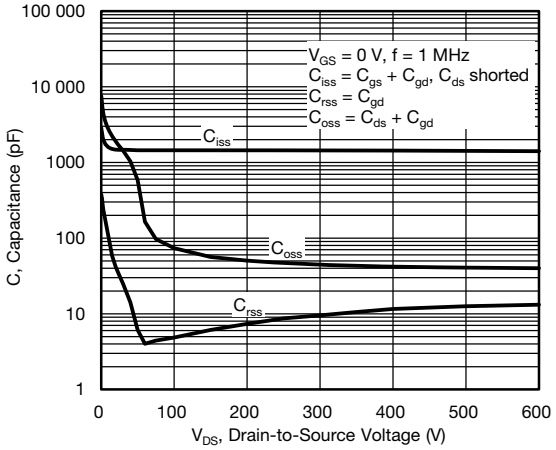



**Fig. 5 - Typical Capacitance vs. Drain-to-Source Voltage**

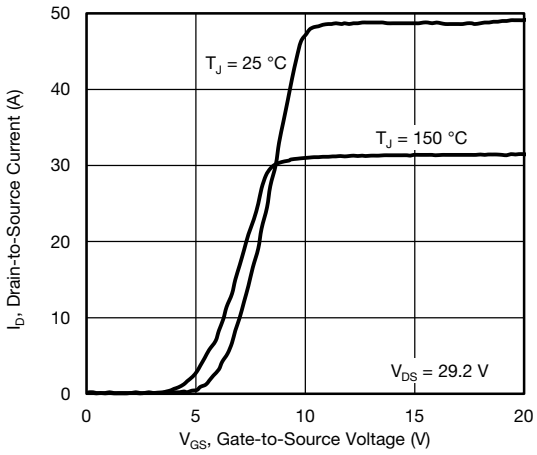



**Fig. 3 - Typical Transfer Characteristics**

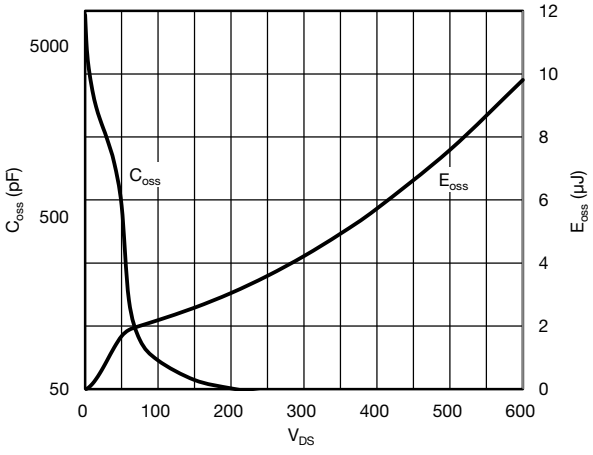



**Fig. 6 - $C_{oss}$ and $E_{oss}$ vs. $V_{DS}$**



For technical questions, contact: hvm@vishay.com

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

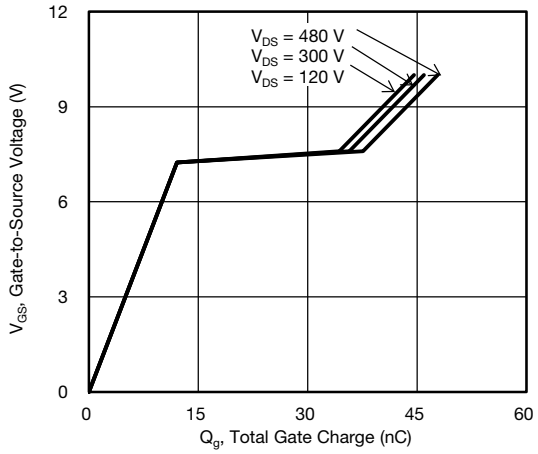



**Fig. 7 - Typical Gate Charge vs. Gate-to-Source Voltage**

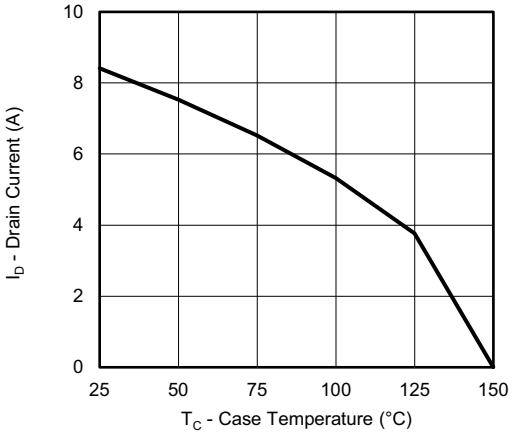



**Fig. 10 - Maximum Drain Current vs. Case Temperature**

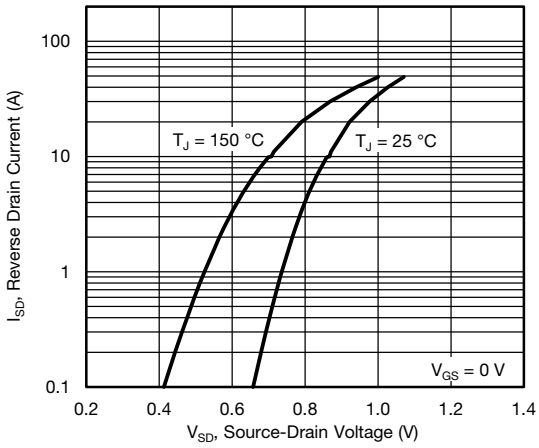



**Fig. 8 - Typical Source-Drain Diode Forward Voltage**

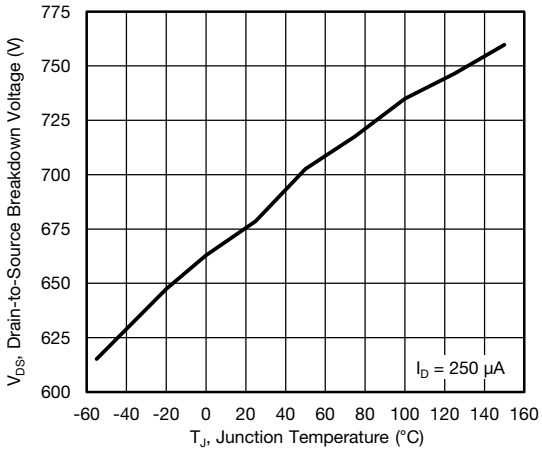



**Fig. 11 - Temperature vs. Drain-to-Source Voltage**

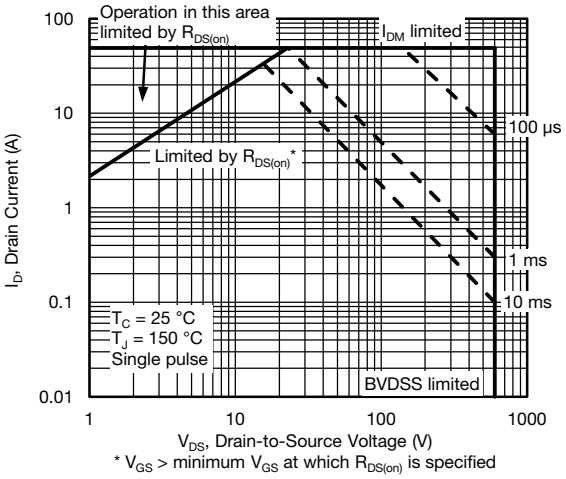



**Fig. 9 - Maximum Safe Operating Area**


For technical questions, contact: hvm@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

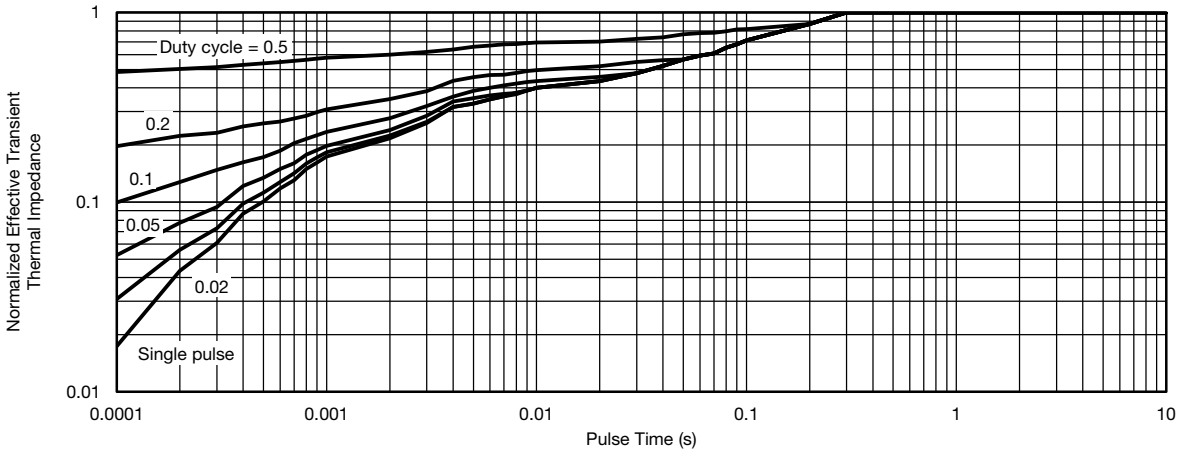



**Fig. 12 - Normalized Thermal Transient Impedance, Junction-to-Case**

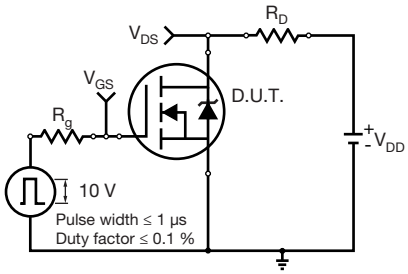



**Fig. 13 - Switching Time Test Circuit**

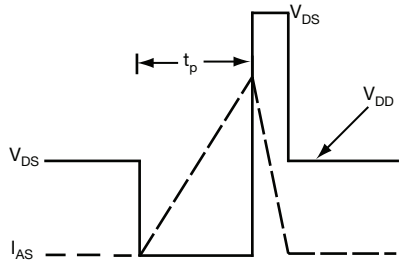



**Fig. 16 - Unclamped Inductive Waveforms**

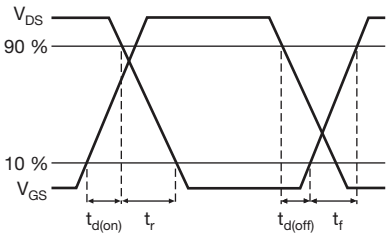



**Fig. 14 - Switching Time Waveforms**

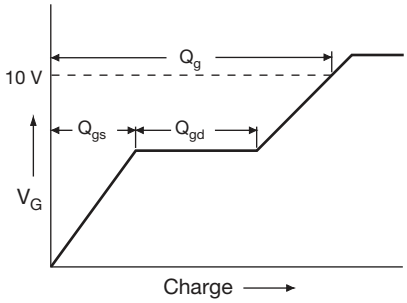



**Fig. 17 - Basic Gate Charge Waveform**

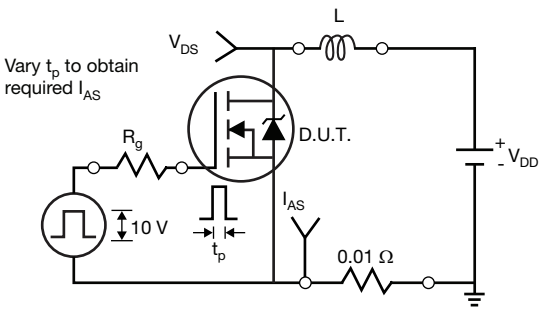



**Fig. 15 - Unclamped Inductive Test Circuit**

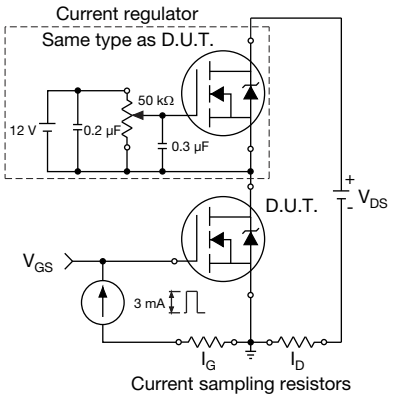



**Fig. 18 - Gate Charge Test Circuit**


For technical questions, contact: hvm@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

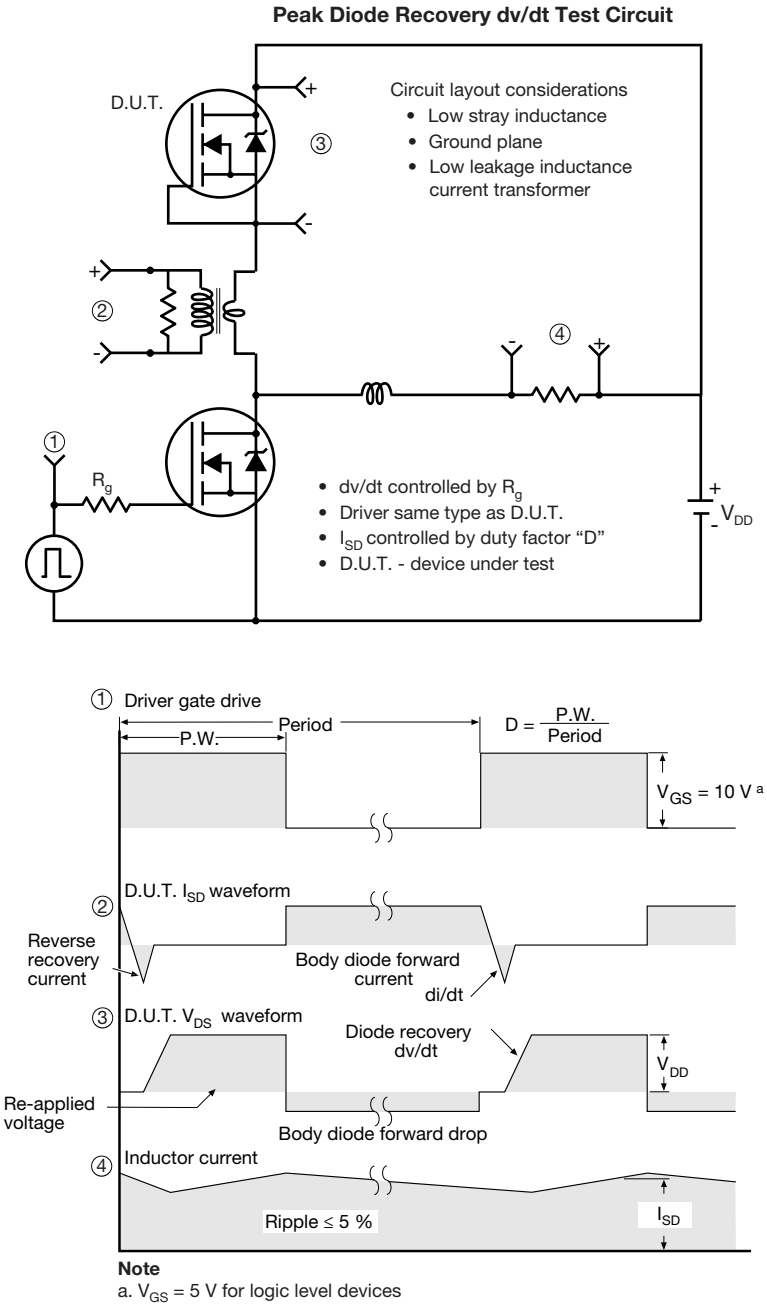
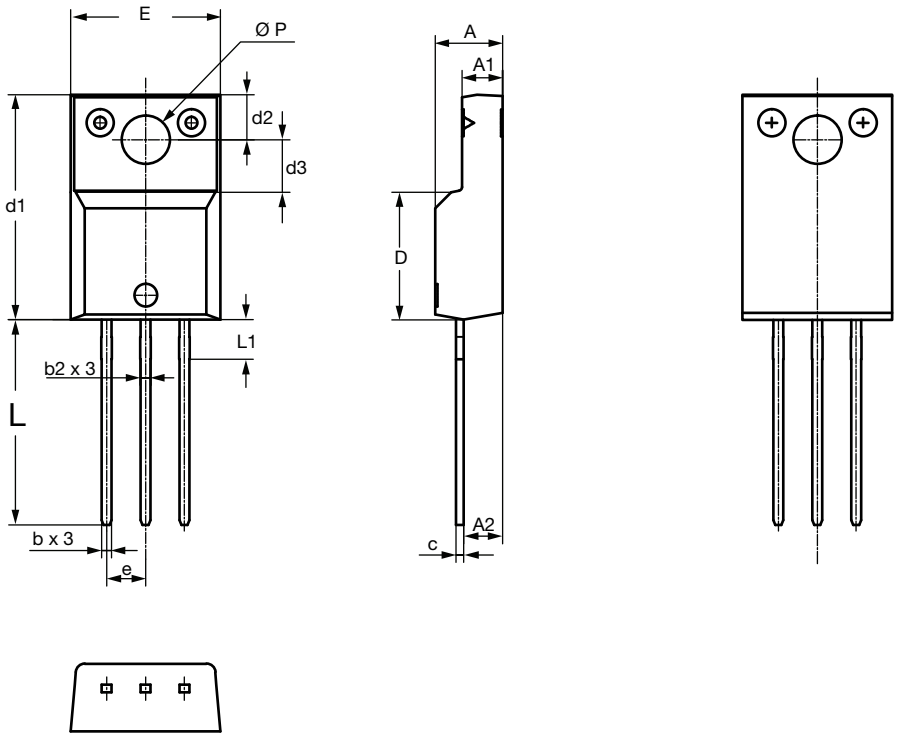



**Fig. 19 - For N-Channel**



THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

# TO-220 FULLPAK Thin Lead




| SYMBOL | DIMENSIONS | | | |
|---|---|---|---|---|
| | MILLIMETERS | | INCHES | |
| | MIN. | MAX. | MIN. | MAX. |
| A | 4.30 | 4.70 | 0.169 | 0.185 |
| A1 | 2.50 | 2.90 | 0.098 | 0.114 |
| A2 | 2.40 | 2.80 | 0.094 | 0.110 |
| b | 0.60 | 0.80 | 0.024 | 0.031 |
| b2 | 0.60 | 0.90 | 0.024 | 0.035 |
| c | - | 0.60 | - | 0.024 |
| D | 8.30 | 8.70 | 0.327 | 0.342 |
| d1 | 14.70 | 15.30 | 0.579 | 0.602 |
| d2 | 2.90 | 3.10 | 0.114 | 0.122 |
| d3 | 3.30 | 3.70 | 0.130 | 0.146 |
| E | 9.70 | 10.30 | 0.382 | 0.406 |
| e | 2.50 | 2.70 | 0.098 | 0.106 |
| L | 13.40 | 13.80 | 0.528 | 0.543 |
| L1 | 1.00 | 2.80 | 0.039 | 0.110 |
| Ø P | 3.00 | 3.40 | 0.118 | 0.134 |

ECN: E20-0684-Rev. D, 28-Dec-2020
DWG: 6021



For technical questions, contact:

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

# Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, “Vishay”), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

*© 2026 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED*



THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

ENTEGRECİ

Bu belge www.entegreci.com üzerinden sunulmaktadır.

# Elektronik komponent tedarikinde Entegreci

Entegreci, Eskişehir merkezli, Türkiye geneline satış yapan bir elektronik komponent mağazasıdır. Entegreler (IC), mikrodenetleyiciler, transistörler, diyotlar, pasif elemanlar, konnektörler, modüller ve geliştirme kartları tek adetten seri üretim adetlerine kadar satılır. Ürün sayfalarında güncel stok durumunu, fiyatı ve datasheet bağlantısını bulabilirsiniz.

### Parça koduyla arama

Üretici parça numarasını yazın; stok ve fiyatı hemen görün.

**www.entegreci.com**

### Ürün kategorileri

Entegreden kapasitöre tüm elektronik komponent kategorileri.

**Kategorilere göz atın**

### Üreticiler

Aradığınız üreticinin ürünlerini tek sayfada inceleyin.

**Üreticileri görün**

### Toplu alım ve teklif

Listede olmayan ya da yüksek adetli parçalar için teklif isteyin.

**Teklif isteyin**

**www.entegreci.com** | **destek@entegreci.com** | **0850 305 90 34**

Entegreci is an online electronic components store based in Türkiye. Search by manufacturer part number to see stock, prices and datasheets for integrated circuits, microcontrollers, transistors, passive components and connectors, or request a quote for parts that are not listed.

Bu sayfa Entegreci tarafından eklenmiştir. Belgenin önceki sayfaları asıl yayıncısına aittir ve içeriği değiştirilmemiştir; en güncel sürüm için belgenin yayıncısına başvurun.